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### Tuning the thermoelectric properties of metallo-porphyrins

Qusiy H. Al-Galiby<sup>†a,b</sup>, Hatef Sadeghi<sup>†a</sup>, Laith A. Algharagholy<sup>†a,c,d</sup>, Iain Grace<sup>†a</sup> and \*Colin Lambert<sup>†a</sup>

We investigated the thermoelectric properties of metalloporphyrins connected by thiol anchor groups to gold electrodes. By varying the transition metal-centre over the family Mn, Co, Ni, Cu, Fe, and Zn we are able to tune the molecular energy levels relative to the Fermi energy of the electrodes. The resulting single-molecule room-temperature thermopowers range from almost zero for Co and Cu centres, to +80  $\mu$ V/K and +230  $\mu$ V/K for Ni and Zn respectively. In contrast, the thermopowers with Mn(II) or Fe(II) metal centres are negative and lie in the range -280 to -260  $\mu$ V/K. Complexing these with a counter anion to form Fe(III) and Mn(III) changes both the sign and magnitide of their thermopowers to +218 and +95 respectively. The room-temperature power factors of Mn(II), Mn(III), Fe(III), Zn and Fe(II) porphyrins are predicted to be 5.9×10<sup>-5</sup> W/m.K<sup>2</sup>, 5.4×10<sup>-4</sup> W/m.K<sup>2</sup>, 9.5×10<sup>-4</sup> W/m.K<sup>2</sup>, 1.6×10<sup>-4</sup> W/m.K<sup>2</sup> and 2.3×10<sup>-4</sup> W/m.K<sup>2</sup> respectively, which makes these attractive materials for molecular-scale thermoelectric devices.

#### Introduction

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The ability to generate a voltage from a temperature gradient has been known since the early 19th century<sup>1</sup>. This Seebeck effect is exploited to generate electricity from sources of waste heat such as automobile exhausts and industrial manufacturing processes and the inverse process (i.e. the Peltier effect) is used in cascade coolers for on-chip cooling of electronic devices<sup>2-5</sup>. Nowadays, a great deal of effort is aimed at increasing the efficiency of these effects and identifying the parameters that control the thermoelectric performance of materials and devices<sup>6-12</sup>. Although most common thermoelectric materials are inorganic, there is growing interest in the development of organic thermoelectric materials<sup>6-10, 18-22</sup>, partly because many widely-deployed inorganic thermoelectric materials are toxic, expensive to process and have limited global supplies. Since the thermoelectric performance of inorganic materials can be enhanced by taking advantage of nanostructuring  $^{\rm 13-19}\!,$  there is particular interest in exploiting the room-temperature properties of single-molecules attached to nanogap electrodes, which can be regarded as the ultimate nanostructured devices. In what follows our aim is to explore the potential for thermoelectricity of single-molecule metallo-porphyrin junctions. Porphyrins are attractive as building blocks for molecular-scale devices. because they are conjugated, rigid, chemically stable and form metalloporphyrins by coordinating a variety of metallic ions<sup>20-28.</sup>

From the point of view of optimising thermoelectric properties, junctions formed from these molecules are of interest, because by varying the metal atom residing in the core of the organic porphyrin framework, it should be possible to tune the molecular energy levels relative to the Fermi energy  $E_F$  of the electrodes. If energy levels can be caused to sit close to  $E_F$ , then this is expected to lead to transport resonances, which enhance the thermopower. In what follows, we shall demonstrate that this is indeed the case and that large positive and negative thermopowers are achievable.

#### Thermoelectric coefficients

To understand how transport resonances lead to high thermoelectric performance, we note that in the linear-response regime, the electric current I and heat current  $\dot{Q}$  passing through a device is related to the voltage difference  $\Delta V$  and temperature difference  $\Delta T$  by<sup>29, 30</sup>

$$\begin{pmatrix} I \\ \dot{Q} \end{pmatrix} = \frac{1}{h} \begin{pmatrix} e^2 L_0 & \frac{e}{T} L_1 \\ e L_1 & \frac{1}{T} L_2 \end{pmatrix} \begin{pmatrix} \Delta V \\ \Delta T \end{pmatrix}$$
(1)

where T is the reference temperature. Since transport through single molecules is phase-coherent, even at room temperature, the coefficients  $L_n$  are given by  $L_n = L_n^{\dagger} + L_n^{\downarrow}$  (n = 0, 1, 2), where

$$L_n^{\sigma} = \int_{-\infty}^{\infty} (E - E_F)^n T^{\sigma}(E) \left(-\frac{\partial f(E,T)}{\partial E}\right) dE$$
(2)

In this expression,  $T^{\sigma}(E)$  is the transmission coefficient for electrons of energy E, spin of  $\sigma = [\uparrow, \downarrow]$  passing through the molecule from one electrode to the other<sup>31</sup> and f(E,T) is Fermi distribution function defined as  $f(E,T) = [e^{(E-E_F)/k_BT} + 1]^{-1}$  where  $k_B$  is Boltzmann's constant. Equation (1) can be rewritten in terms of the electrical conductance (*G*), thermopower (*S*), Peltier coefficient ( $\Pi$ ), and the electronic contribution to the thermal conductance ( $\kappa_e$ ):

$$\begin{pmatrix} \Delta V \\ \dot{Q} \end{pmatrix} = \begin{pmatrix} 1/G & S \\ \prod & \kappa_e \end{pmatrix} \begin{pmatrix} I \\ \Delta T \end{pmatrix}$$
(3)

where

<sup>&</sup>lt;sup>a.</sup> Quantum Technology Centre, Lancaster University, Lancaster LA1 4YB, UK.

<sup>&</sup>lt;sup>b.</sup> Physics Department ,Al-Qadisiyah University, Diwaniyah, 58002, IRAQ
<sup>c.</sup> College of Basic Education, Sumer University, Al-Refayee, Thi-Qar 64001, IRAQ

<sup>&</sup>lt;sup>d</sup> College of Computer Science and Mathematics, Al-Qadisiyah University, Al-Qadisiyah ,Diwaniyah, 58002, IRAQ.

<sup>+</sup> Authors contributed equally.

<sup>\*</sup>Corresponding author: c.lambert@lancaster.ac.uk, qusiyalgaliby@gmail.com

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$$G = \frac{e^2}{h}L_0 \tag{4}$$

$$S = -\Delta V / \Delta T = \frac{1}{eT} \frac{L_1}{L_0}$$
(5)

$$\Pi = \frac{1}{e} \frac{L_1}{L_0} \tag{6}$$

 $\kappa_e = \frac{1}{hT} \left( L_2 - \frac{1}{L_0} \right) \tag{7}$ 

From the above expressions, the electronic thermoelectric figure  $ZT_e = S^2 GT/\kappa_e$  is given by

$$ZT_e = \frac{(L_1)^2}{L_0 L_2 - (L_1)^2}$$
(8)

For *E* close to  $E_F$ , if *T*(*E*) varies only slowly with *E* on the scale of  $k_B T$  then these formula take the form<sup>32</sup>:

$$G(T) \approx \left(\frac{2e^2}{h}\right) T(E_F),\tag{9}$$

$$S(T) \approx -\alpha eT \left(\frac{d \ln I(E)}{dE}\right)_{E=E_F},$$
(10)
$$\kappa_e \approx L_0^{\sigma} TG,$$
(11)

where  $\alpha = \left(\frac{k_B}{e}\right)^2 \frac{\pi^2}{3}$  is the Lorentz number. Equation (10) demonstrates that *S* is enhanced by increasing the slope of ln *T*(*E*) near *E*=*E*<sub>*F*</sub> and hence it is of interest to explore whether or not the ability to vary the metal centre in metallo-porphyrins can be used to move resonances close to *E*<sub>*F*</sub>.

#### Methods

As shown in Figure 1, the porphyrin monomer of interest consists of four pyrrole cores (the inner ring n-system) with side groups comprising a phenyl ring connected via two oxygen atoms to electrically-inert alkyl groups (-C8H17). The core of porphyrin is connected via thiol anchor groups to gold electrodes. Our aim



Figure 1: Porphyrin-based molecular structures (a) without metallic atom, (b) with different metallic atoms  $\chi$  = Co, Cu, Fe, Mn, Ni, and Zn

in this paper is to investigate the effect on thermoelectric performance of varying the metal atom  $\chi$  over the series of  $\chi$  = Co, Cu, Fe, Mn, Ni, and Zn.

To calculate the electrical properties of each metallo-porphyrin, we used the spin density functional theory (DFT) code SIESTA<sup>33</sup> which employs Troullier-Martins pseudopotentials to represent the potentials of the atomic cores<sup>34</sup>, and a local atomic-orbital basis set. A double-zeta polarized basis set was used for all atoms and the generalized gradient approximation (GGA-PBE) for the exchange and correlation functionals<sup>35, 36</sup>. The Hamiltonian and overlap matrices are calculated on a real-space grid defined by a plane-wave cut-off of 150 Ry. Each molecule was relaxed to the optimum geometry until the forces on the atoms are smaller than 0.02 eV/Å and in case of the isolated molecules, a sufficiently-

large unit cell was used to avoid inter-cell interactions. All porphyrin molecules with metallic atoms  $\chi$  were found to be slightly twisted after relaxation.

After obtaining the relaxed geometry of each isolated molecule, the molecules were placed between two gold electrodes, as shown in Figure 2. For structures such as those shown in Figure 2, the central region of the junction is composed of a single molecule attached to two gold (111) leads. The equilibrium distance between the sulfur atom of each anchor group and the centre of the apex atom of each gold pyramid was initially 2.5 Å. After geometry optimization the distance changed slightly from the initial value to a final value of 2.63 Å.



**Figure 2.** An example of an optimized junction configuration. To reduce the computational cost, we replace the electrically-inert alkyl group (-C8H17) with a methyl group (-CH3).

The *d*-orbitals of metallic atoms could be partially filled, so for each molecular junction, we carried out a spin-polarized calculation to obtain the electron and spin transport properties, using the Gollum quantum transport code<sup>37</sup> to compute the spin-dependent transmission coefficients  $T^{\sigma}(E)$  for electrons of energy *E* passing from the left gold electrode to the right electrode. Gollum is a next-generation code, born out of the SMEAGOL code<sup>38</sup> and uses the mean-field Hamiltonian and overlap matrices obtained from density functional theory to compute transport properties of a wide variety of nanostructures. After computing  $T^{\sigma}(E)$ , we evaluated the zero-bias thermoelectric coefficients over a wide range of Fermi energies and temperatures by using equations (1-8).

#### **Results and Discussion**

For each metallo-porphyrin P- $\chi$  in Figure 1b, the charge transfer between the metal atom and the porphyrin framework was calculated (as shown in Table S1 of SI). As expected, the calculations show that all metal atoms donate electrons to the porphyrin host. As examples, Figure 3 shows the frontier orbitals, spin-dependent and total transmission coefficients of the bare porphyrin (left) and Fe-porphyrin (right) relative to the DFT-predicted Fermi energy  $E_F^{DFT}$ . Results for other molecules are shown in figures (S1-S7) of the SI.

Figure 3(a) shows that for the bare porphyrin, the transmission T(E) at the DFT-given Fermi level ( $E_F^{DFT}$ , indicated by the vertical black line) is closest to the HOMO resonance and the slope of the curve is negative. On the other hand for the Fe porphyrin, figure 3b shows that the Fermi level is nearest to the LUMO resonance and the slope is positive in both Figures 3b. Hence from equation (10), one expects the thermopower of the former (latter) to be positive (negative).

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Figure 3. Top panels: Iso-surfaces of frontier molecular orbitals of the bare porphyrin (Porphyrin -bare) and the iron-porphyrin (Porphyrin-Fe(II) obtained using spin- polarized DFT. Red corresponds to positive and blue to negative regions of the wave functions. Lower panels: The spin-dependent and total transmission coefficients as a function of energy for bare porphyrin (left) and porphyrin-Fe (right).



**Figure 4.** (colour online) DFT spin-dependent room-temperature electrical conductance (in units of  $G_0 = 2e^2/h = 77 \ \mu$ Siemens) over a range of Fermi energies for (a) the P-bare and P-Co, Cu, Ni and Zn and (b) the P-bare and P-Fe(II), P-Mn(II), PFe(III) and PMn(III). (c) Room-temperature values of G for P-bare, P-Co, P-Cu, P-Ni, P-Zn, P-Fe(II) and P-Mn(II) are 3.43 ×10<sup>-3</sup>, 1.05 ×10<sup>-3</sup>, 3.48 ×10<sup>-3</sup>, 8.7 ×10<sup>-4</sup>, 1.7 ×10<sup>-2</sup> and 2.1 ×10<sup>-2</sup> respectively. (d) Room-temperature values of G for the porphyrins Mn(II), Mn(III), Fe(II) and Fe(III). The lines in (c) and (d) are guides to the eye.

Figure 4 shows the total room temperature electrical conductance for each P- $\chi$ . Figure 4(a) shows that the bare (dotted line) and Co, Cu, Zn and Ni porphyrins (solid lines), exhibit HOMO-dominated conductance at the DFT Fermi energy,



**Figure 5**. The room-temperature thermopower S and figure of merit ZT<sub>e</sub>. 4(a) and (c) show plots of S and ZT<sub>e</sub> over a range of Fermi energies  $E_F$  relative to the DFT-predicted Fermi energy  $E_F^{DFT}$ . The right column shows room-temperature values obtained using  $E_F = E_F^{DFT}$  of S and ZT<sub>e</sub> for each metallo-porphyrin.

whereas Figure 4b shows that for the Mn(II) and Fe(II) porphyrins, we obtain LUMO-dominated conductance. Figure 4(c) shows the room-temperature conductance at the DFT Fermi energy and shows that the pattern of increasing conductance is Ni < Co < Cu < Bare < Mn(II) < Zn < Fe(II). The conductance of porphyrin-Cu ( $3.49 \times 10^{-3} \text{ G}_0$ ) is slightly higher than of porphyrin-bare, ( $3.43 \times 10^{-3} \text{ G}_0$ ). This order is in agreement with previous measurements on similar molecules<sup>25</sup>. We are not aware of conductance measurements of the Mn, Zn and Fe porphyrins.

In the case of Mn and Fe, metalloporphyrins exist more commonly as P-M(III) in the presence of a counter anion. Since it is straightforward to oxidise/reduce between Fe(II)/(III) and Mn(II)/(III), we have also computed all thermoelectric properties for Fe(III) and Mn(III) complexed with a Cl<sup>-</sup> counter ion (See SI Figures S9–S15). The resulting room-temperature conductances are shown in Figure 4b reveals that in the presence of the counter anion, transport becomes LUMO dominated. Figure 4d compares the room-temperature conductances of Fe(II)/(III) and Mn(II)/(III) and shows that the presence of a counter anion increases the electric conductance.

Figures 5b and 5d show results for the Seebeck coefficient (thermopower) *S* and electronic contribution to the figure of merit  $ZT_e$  at room temperature. It is well-known that DFT can give inaccurate value for the Fermi energy and therefore Figures 5a and 5c show corresponding results for a range of Fermi energies  $E_F$  relative to the DFT-predicted Fermi energy  $E_F^{DFT}$ , whereas Figures 5b and 5d show room-temperature values of *S* and  $ZT_e$  for each metalloporphyrin, evaluated at the DFT Fermi energy. Figure 5b demonstrates that both the magnitude and sign of thermopower *S* are sensitive to the netal atoms at the centre of the porphyrin monomer, which determine the location of transport resonances relative to the Fermi energy. Furthermore, in the case of Fe and Mn, Figure 5b reveals that the sign of the thermopower can be switched from negative to positive upon complexation with Cl<sup>-</sup>, due to their switching from HOMO to LUMO dominated transport.

At the DFT-predicted Fermi energy, the highest values of the thermopower are obtained in the presence of Mn, Fe and Zn, for which S takes values -280, -260 and +230  $\mu$ V/K respectively, all of which have a greater magnitude than the

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**Figure 6:** (a, b, c and d) represent the electrical conductance, Seebeck coefficients *S* (thermopower), electronic contribution to the figure of merit  $ZT_e$  and electronic contribution to the thermal conductance  $k_e$  over a range of temperatures, evaluated at  $E_F = E_F^{DFT}$ .



product  $GS^2$ , while figure (b) shows the power factor  $P = S^2GL/A$ evaluated at  $E_F = E_F^{DFT}$ . The lower figure (c) shows room-temperature values of power factor  $P = S^2GL/A$  for each metallo-porphyrin.

thermopower of the bare porphyrin (165  $\mu$ V/K). The lowest values of all are obtained for Co, closely followed by Cu. For Fe(III)-P we obtain S= +218  $\mu$ V/K at room temperature and for Mn(III)-P we find S= +95  $\mu$ V/K. Corresponding results for the electronic contribution to the figure of merit *ZT<sub>e</sub>* are shown in Figure 5d. The highest values of *ZT<sub>e</sub>* are obtained in the presence of Zn, Mn and Fe, reflecting the high values of their thermopowers and conductances.

Figure 6 shows the electrical conductance G, Seebeck coefficients S (thermopower), electronic contribution to the figure of merit  $ZT_e$  and electronic contribution to the thermal conductance  $k_e$  as a function of temperature,

obtained using the DFT-predicted Fermi energy  $E_F^{DFT}$ . These results show that the magnitudes of all quantities increase with increasing temperature.

A crucial quantity determining the efficiency of a thermoelectric material or device is the dimensionless figure of merit  $ZT = S^2 GT/\kappa$ , whose denominator  $\kappa$  is the total thermal conductance due to both phonons and electrons. This differs from the electronic figure of merit  $ZT_e = S^2 GT/\kappa_e$  whose denominator contains only the thermal conductance due to electrons. For a bulk material, ZT is often written in the form  $= (P/\kappa)T$ , where  $\kappa$  is the total thermal conductivity and P is the power factor defined by as P = $S^2\sigma$ , where  $\sigma$  is the electrical conductivity. In practice for a single molecule, ZT is difficult to measure experimentally, because the thermal conductance  $\kappa$  of a single molecule is not directly accessible. However the numerator of ZT (i.e. the power factor P) is accessible. The notion of conductivity is not applicable to transport through single molecules, but to compare with literature values for bulk materials, we define  $\sigma = GL/A$ , where L and A are equal to the length and the cross-sectional area of the molecule respectively. In what follows, the values L = 4.0 nm and  $A = 1.8 \text{ nm}^2$  are used. From the results of Figure 5, the quantity  $GS^2$  and power factors  $P = S^2 GL/A$  for each of the studied molecules are shown in Figure 7.

These results show that Mn, Mn(III), Fe(III), Zn and Fe porphyrins have the highest power factors of  $5.9 \times 10^{-5}$  W/m.K<sup>2</sup>,  $5.4 \times 10^{-4}$  W/m.K<sup>2</sup>,  $9.5 \times 10^{-4}$  W/m.K<sup>2</sup>,  $1.6 \times 10^{-4}$  W/m.K<sup>2</sup> and  $2.3 \times 10^{-4}$  W/m.K<sup>2</sup> respectively.

#### Conclusion

We have used spin-dependent density functional theory to study the thermoelectric properties of metallo-porphyrin monomers with central metal atoms chosen from the series Co, Cu, Fe, Mn, Ni, and Zn. We found that the energies of transport resonances can be tuned through the choice of central metal atom, leading to large negative thermopowers in the range -280 to -260  $\mu$ V/K for Mn(II)- and Fe(II)-porphyrins and a large positive thermopower of +230 µV/K in the case of Zn-porphyrin. These Seebeck coefficients are almost independent of temperature at room temperature and are significantly larger than recently-measured values of S at room temperature. For example, measured values include 8.7, 12.9 and 14.2  $\mu V/K$  for 1,4-benzenedithiol (BDT), 4,4'-dibenzenedithiol, and 4,4"-tribenzenedithiol respectively<sup>39</sup>, -1.3 to 8.3  $\mu V/K$  for the benzene-based series of benzene-dithiol (BDT). 2.5-dimethyl-1.4-benzenedithiol (BDT2Me). 2,3,5,6-tetrachloro-1,4-benzenedithiol (BDT4Cl), 2,3,5,6-tetraflouro-1,4-benzenedithiol (BDT4F) and BDCN<sup>40, 41</sup>, 7.7 to 15.9  $\mu$ V/K for the series BDT, DBDT, TBDT and DMTBDT<sup>42</sup>, -12.3 to 13.0  $\mu$ V/K for a series of amine-Au and pyridine-Au linked molecules<sup>43</sup> and -8.9 to -33.1  $\mu$ V/K for fullerene-based single-molecule junctions<sup>9, 40, 44</sup>. Furthermore Znporphyrins have a large electronic figures of merit. At room temperature, we obtain power factors of 5.9×10<sup>-5</sup> W/m.K<sup>2</sup> for Mn-porphyrin, 5.4×10<sup>-4</sup> W/m.K<sup>2</sup> For Mn(III)-porphyrin, 9.5×10<sup>-4</sup> W/m.K<sup>2</sup> for Fe(III)-porphyrin, 1.6×10<sup>-4</sup> W/m.K<sup>2</sup> for Zn-porphyrin and 2.3×10<sup>-4</sup> W/m.K<sup>2</sup> for Fe(II)-porphyrin. These compare favourably with power factors of other organic materials, whose reported values range from 0.016 µW/m.K<sup>2</sup> and 0.045 µW/m.K<sup>2</sup> for Polyaniline and Polypyrole respectively  $^{45}$ , to 12  $\mu\text{W/m.K}^2$  for PEDOT:PSS  $^{46}$  and (12  $\mu\text{W/m.K}^2$ for C<sub>60</sub>/Cs<sub>2</sub>Co<sub>3</sub> Dph-BDT<sup>47</sup>.

This ability to tune the thermoelectric properties of single molecules, combined with the fact that the Seebeck coefficient is an intrinsic property, which does not scale with the number of molecules conducting in parallel, suggests that self-assembled monolayers or few-layers of metallo-porphyrins have potential for high-performance conversion of heat into electricity and efficient Peltier cooling. The technical step of translating single-molecule properties into thin films is a significant challenge and a major programme of

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fundamental research will be needed to fully address this issue. Nevertheless our recent theoretical study of the thermal conductance of single alkane and alkyne molecules compares favourably with experiments on thin films of such molecules<sup>48</sup> and gives us confidence single-molecule thermal properties do survive in molecular films. Furthermore many of the techinical barriers to be overcome are already clear. For example, to take advantage of the quantum effects described in this paper, the film thickness should be less than the electronic phase-breaking length, which at room temperature is of order 3nm<sup>49-51</sup>. If molecules are first deposited onto a bottom electrode, then the top electrode should be added without destroying the integrity of the molecular film. One solution to the "top-contact problem" would be to use a two-dimensional electrode material such as graphene as the top electrode. Success would depend on alignment or misalignment of the two contacts and the presence of step edges and other defects in the transferred twodimensional material. In the case of hexagonal materials such as graphene, such defects would include non-hexagonal rings<sup>52</sup>, which would alter the binding energy and electronic coupling to molecular anchor groups. It is well established that both molecules and electrodes should be treated in an holistic manner when designing single-molecule junctions<sup>53</sup> and the same will be true of thin films. For the purpose of increasing ZT and reducing the thermal conductance, one strategy will involve choosing electrode materials which maximise phonon scattering at the molecule-electrode interface and taking advantage of phonon filtering by the electrodes, as a described in<sup>48</sup>. In addition, intermolecular interactions may utilised to optimise thin-film properties beyond those accessible to single molecules.

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#### References

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Published on 05 January 2016. Downloaded by University of Lancaster on 05/01/2016 11:21:34

1 T.J. Seebeck, Annalen der Physik, 82 (1826) 253-286.

2 X. Chen, L. Chen, J. Guo, J. Chen, international journal of hydrogen energy, 36Physics, 16 (2014) 093029. (2011) 6099-6104.

3 S. Kumar, S.D. Heister, X. Xu, J.R. Salvador, G.P. Meisner, Journal of electronicNature materials, 4 (2005) 335-339. materials, 42 (2013) 665-674. 39 P. Reddy, S.-Y. Jang, R.A. Segalman, A. Majumdar, Science, 315 (2007) 4 B.I. Ismail, W.H. Ahmed, Recent Patents on Electrical & Electronic Engineering1568-1571. 40 J.A. Malen, S.K. Yee, A. Majumdar, R.A. Segalman, Chemical Physics Letters, (Formerly Recent Patents on Electrical Engineering), 2 (2009) 27 39.

5 D. Voneshen, K. Refson, E. Borissenko, M. Krisch, A. Bosak, A. Piovano, E. Cemal, 491 (2010) 109-122. 41 K. Baheti, J.A. Malen, P. Doak, P. Reddy, S.-Y. Jang, T.D. Tilley, A. Majumdar, M. Enderle, M. Gutmann, M. Hoesch, Nature materials, 12 (2013) 1028-1032. 6 M. Bürkle, L.A. Zotti, J.K. Viljas, D. Vonlanthen, A. Mishchenko, T. Wandlowski, R.A. Segalman, Nano letters, 8 (2008) 715-719. M. Mayor, G. Schön, F. Pauly, Physical Review B, 86 (2012) 115304. 42 J.A. Malen, P. Doak, K. Baheti, T.D. Tilley, A. Majumdar, R.A. Segalman, Nano letters, 9 (2009) 3406-3412. 7 P. Chaikin, J. Kwak, Review of Scientific Instruments, 46 (1975) 218-220. [8] S.-H. Ke, W. Yang, S. Curtarolo, H.U. Baranger, Nano letters, 9 (2009) 1011-43 J.R. Widawsky, P. Darancet, J.B. Neaton, L. Venkataraman, Nano letters, 12

1014. (2011) 354-358. 9 C. Evangeli, K. Gillemot, E. Leary, M.T. González, G. Rubio-Bollinger, C.J. Lambert, 44 S.K. Yee, J.A. Malen, A. Majumdar, R.A. Segalman, Nano letters, 11 (2011) 4089-4094 N. Agrait, Nano letters, 13 (2013) 2141-2145. 10 A.A. Balandin, Nature Materials, 10 (2011) 569-581.

45 A. Shakouri and S. Li, S. In Thermoelectrics, 1999. Eighteenth International Conference on (pp. 402-406). IEEE. 12 H. Sadeghi, S. Sangtarash, C.J. Lambert, Beilstein Journal of Nanotechnology, 6

(2015) 1176-1182. 46 H. Shi, C. Liu, J. Xu, H. Song, Q. Jiang, B. Lu, and F. Jiang, Int. J. 13 R. Venkatasubramanian, E. Siivola, T. Colpitts, B. O'quinn, Nature, 413 (2001)Electrochem. Sci 9 (2014): 7629-43.

47 M. Sumino, K. Harada, M. Ikeda, S. Tanaka, K. Miyazaki, C. & Adachi, Applied Physics Letters (2011) 99.9: 093308.

14 T. Harman, P. Taylor, M. Walsh, B. LaForge, Science, 297 (2002) 2229-2232. 15 B. Poudel, Q. Hao, Y. Ma, Y. Lan, A. Minnich, B. Yu, X. Yan, D. Wang, A. Muto, D.

11 H. Sadeghi, S. Sangtarash, C.J. Lambert, Scientific reports, 5 (2015) 9514.

Vashaee, Science, 320 (2008) 634-638.

16 X. Liu, D. Wang, J. Shi, APS Meeting Abstracts2011, pp. 30013.

K. Yanagi, S. Kanda, Y. Oshima, Y. Kitamura, H. Kawai, T. Yamamoto, T. 17 Takenobu, Y. Nakai, Y. Maniwa, Nano letters, 14 (2014) 6437-6442.

18 A. Kambili, G. Fagas, V.I. Fal'ko, C. Lambert, Physical Review B, 60 (1999) 15593.

19 G. Fagas, A. Kozorezov, C. Lambert, J. Wigmore, A. Peacock, A. Poelaert, R. Den Hartog, Physical Review B, 60 (1999) 6459.

20 G. Dorough, J. Miller, F.M. Huennekens, Journal of the American Chemical Society, 73 (1951) 4315-4320.

21 G. Sedghi, V.M. García-Suárez, L.J. Esdaile, H.L. Anderson, C.J. Lambert, S. Martín, D. Bethell, S.J. Higgins, M. Elliott, N. Bennett, Nature nanotechnology, 6 (2011) 517 - 523

22 D. Gust, J.D. Roberts, Journal of the American Chemical Society, 99 (1977) 3637-3640

23 Z. Li, M. Smeu, M.A. Ratner, E. Borguet, The Journal of Physical Chemistry C, 117 (2013) 14890-14898.

24 Z. Li, E. Borguet, Journal of the American Chemical Society, 134 (2011) 63-66. 25 Z.-F. Liu, S. Wei, H. Yoon, O. Adak, I. Ponce, Y. Jiang, W.-D. Jang, L.M. Campos, L. Venkataraman, J.B. Neaton, Nano letters, 14 (2014) 5365-5370.

26 Y. Li, J. Yao, S. Zhong, Z. Zou, Current Applied Physics, 11 (2011) 1349-1353.

27 R. Ferradás, V.M. García-Suárez, J. Ferrer, arXiv preprint arXiv:1208.3157, (2012)

28 I. Beletskaya, V.S. Tyurin, A.Y. Tsivadze, R. Guilard, C. Stern, Chemical reviews, 109 (2009) 1659-1713.

29 V.V. Maslyuk, S. Achilles, I. Mertig, Solid State Communications, 150 (2010) 505-509

30 V.M. García-Suárez, R. Ferradás, J. Ferrer, Physical Review B, 88 (2013) 235417. 31 N. Claughton, C. Lambert, Physical Review B, 53 (1996) 6605.

32 V.M. García-Suárez, C.J. Lambert, D.Z. Manrique, T. Wandlowski, Nanotechnology, 25 (2014) 205402.

33 J.M. Soler, E. Artacho, J.D. Gale, A. García, J. Junquera, P. Ordejón, D. Sánchez-Portal, Journal of Physics: Condensed Matter, 14 (2002) 2745.

34 N. Troullier, J.L. Martins, Physical Review B, 43 (1991) 1993.

35 J.P. Perdew, K. Burke, M. Ernzerhof, Physical review letters, 77 (1996) 3865.

36 B. Hammer, L.B. Hansen, J.K. Nørskov, Physical Review B, 59 (1999) 7413.

37 J. Ferrer, C.J. Lambert, V.M. García-Suárez, D.Z. Manrique, D. Visontai, L. Oroszlany, R. Rodríguez-Ferradás, I. Grace, S. Bailey, K. Gillemot, New Journal of

38 A.R. Rocha, V.M. Garcia-Suarez, S.W. Bailey, C.J. Lambert, J. Ferrer, S. Sanvito,

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#### ARTICLE

48 H. Sadeghi, S. Sangtarash and C.J. Lambert, Nano Lett., 2015, 15 (11), pp 7467–7472

49 H. Sadeghi, J.A. Mol, C.S. Lau, G.A.D. Briggs, J. Warner, C.J. Lambert, Proc. Natl. Acad. Sci. (2015), 112, 2658.

50 G. Sedghi, V.M. García-Suárez, L.J. Esdaile, H.L. Anderson, C.J. Lambert, S. Martín, D. Bethell, S.J. Higgins, M. Elliott, N. Bennett, *Nat. Nanotechnol.* (2011), *6*, 517.

51 X. Zhao, C. Huang, M. Gulcur, A.S. Batsanov, M. Baghernejad, W. Hong, M.R. Bryce, T. Wandlowski, *Chem. Mat.* (2013), *25*, 4340.

52 C.J. Lambert and D.L. Weaire, Metallography (1981) 14 (4), 307

53 W. Haiss, C. Wang, R. Jitchati, I. Grace, S. Martín, A.S. Batsanov, S.J. Higgins, M.R. Bryce, C.J. Lambert, P.S. Jensen, R.J. Nichols, J. Phy.s: Condensed Matter 20 (37), 374119